

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Satoshi INOUE; Tatsuya SHIMODA

Serial No.: Rule 53(b) Divisional of Reissue Application No. 10/263,070 filed October 3, 2002  
(which is a Reissue of U.S. Patent No. 6,127,199 issued October 3, 2000)

Filed: December 31, 2003

For: MANUFACTURING METHOD OF ACTIVE MATRIX SUBSTRATE, ACTIVE MATRIX SUBSTRATE AND LIQUID CRYSTAL DISPLAY DEVICE

Docket No.: 040852.98

INFORMATION DISCLOSURE STATEMENT

Director of the U.S. Patent and Trademark Office  
Washington, D.C. 20231

Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the reference(s) listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the reference(s) be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- 2. All of the references were cited by or submitted to the Office in parent application No. 10/263,070, filed October 3, 2002, of which this application is a divisional. Thus, copies of these references are not attached. 37 CFR §1.98(d).

Respectfully submitted,

  
James A. Oliff  
Registration No. 27,075

Yong S. Choi  
Registration No. 43,324

JAO:YSCdmw

Date: December 31, 2003  
**OLIFF & BERRIDGE, PLC**  
**P.O. Box 19928**  
**Alexandria, Virginia 22320**  
**Telephone: (703) 836-6400**

**DEPOSIT ACCOUNT USE  
AUTHORIZATION**  
Please grant any extension  
necessary for entry;  
Charge any fee due to our  
Deposit Account No. 15-0461

Form PTO-1449 (REV. 8-83)		US Dept. of Commerce PATENT & TRADEMARK OFFICE	ATTY DOCKET NO. 040852.98	APPLICATION NO. Rule 53(b) Divisional of Application No. 10/263,070		
INFORMATION DISCLOSURE STATEMENT  (Use several sheets if necessary)		APPLICANT(S) Satoshi INOUE; Tatsuya SHIMODA				
		FILING DATE December 31, 2003				
U.S. PATENT DOCUMENTS						
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
		5,747,121	05/1998	Okazaki et al.		
		5,767,930	06/1998	Kobayashi et al.		
		5,807,772	09/1998	Takemura		
		5,888,839	03/1999	Ino et al.		
		5,468,521	11/1995	Kanai et al.		
		5,008,218	04/1991	Kawachi et al.		
		5,693,541	12/1997	Yamazaki et al.		
		5,589,962	12/1996	Yamamoto et al.		
		5,527,649	06/1996	Sato et al.		
		5,926,735	07/1999	Yamazaki et al.		
FOREIGN PATENT DOCUMENTS						
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS
		JP-A-6-291291	10/1994	JAPAN		
		JP-A-8-288522	11/1996	JAPAN		
		JP-A-61-231714	10/1986	JAPAN		
		JP-A-8-62591	03/1996	JAPAN		
		WO 98/09333	03/1998	WIPO		
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)						
		Sameshima, T. "Laser Beam Application to Thin Film Transistors," <u>Applied Surface Science 96-98</u> , (1996), pp. 352-358.				
EXAMINER					DATE CONSIDERED	
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.						